

	<h2 style="color: red;">FQB4N50TM</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: FQB4N50TM
	Hersteller / Marke: AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung: MOSFET N-CH 500V 3.4A D2PAK
	Datenblätter:  FQB4N50TM.pdf
	RoHS Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 32363 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	FQB4N50TM
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 500V 3.4A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32363 pcs Stock
detaillierte Beschreibung	N-Channel 500V 3.4A (Tc) 3.13W (Ta), 70W (Tc)
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 70W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	500V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.4A (Tc)
Rds On (Max) @ Id, Vgs	2.7 Ohm @ 1.7A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	13nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	460pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Tape & Reel (TR)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)


















































FQB4N50TM ist neu im Original, Suche FQB4N50TM Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB4N50TM AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB4N50TM: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB4N25TM Fairchild/ON Semiconductor MOSFET N-CH 250V 3.6A D2PAK</p>	 <p>FQB4N60C FAIRCHI FQB4N60C FAIRCHI</p>	 <p>FQB4N20TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 3.6A D2PAK</p>	 <p>FQB4N60 Fairchild/ON Semiconductor FQB4N60 FAIRCHILD</p>
 <p>FQB4N20TM VB FQB4N20TM VB</p>	 <p>FQB4N70 Fairchild/ON Semiconductor FQB4N70 FAIRCHILD</p>	 <p>FQB4N50TM Fairchild/ON Semiconductor MOSFET N-CH 500V 3.4A D2PAK</p>	 <p>FQB4N25TM AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 3.6A D2PAK</p>

heiße Teile

Mehr

 FQB3N40TM	 FQB3N60C	 FQB3N80TM	 FQB3N80TM	 FQB3N90TM
 FQB3N90TM	 FQB3P20TM	 FQB3P20TM	 FQB3P50TM	 FQB3P50TM
 FQB44N10	 FQB44N10TM	 FQB44N10TM	 FQB46N15	 FQB46N15TM
 FQB47P06	 FQB47P06TM	 FQB4N20L	 FQB4N20LTM	 FQB4N20LTM
 FQB4N20TM	 FQB4N20TM	 FQB4N25TM	 FQB4N25TM	 FQB4N20TM
 FQB4N50TM	 FQB4N60C	 FQB4N80TM	 FQB4N80TM	 FQB4N90TM
 FQB4N90TM	 FQB4P25TM	 FQB4P25TM	 FQB50N03	 FQB50N06
 FQB50N06C	 FQB50N06L	 FQB50N06LTM	 FQB50N06LTM	 FQB50N06M
 FQB50N06TM	 FQB50N06TM	 FQB50N06TM-NL	 FQB55N06TM	 FQB55N06TM
 FQB55N10	 FQB55N10TM	 FQB55N10TM	 FQB5N20L	 FQB5N30TM

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited